New Product

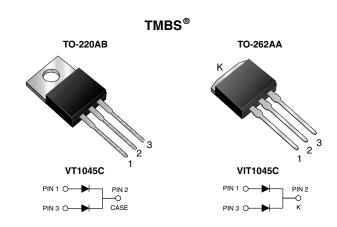


VT1045C, VIT1045C

Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.34$ V at $I_F = 2.5$ A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 5.0 A					
V _{RRM}	45 V				
I _{FSM}	100 A				
V _F at I _F = 5.0 A	0.41 V				
T _J max.	150 °C				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VT1045C	VIT1045C	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	45		V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	10		А		
	per diode		5.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	100		А		
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150		°C		



FREE

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 2.5 A	– T _A = 25 °C	V _F (1)	0.44	-	V
	I _F = 5.0 A			0.49	0.58	
	I _F = 2.5 A	- T _A = 125 °C		0.34	-	
	I _F = 5.0 A			0.41	0.50	
Reverse current per diode	V – 45 V	T _A = 25 °C	I _R (2)	-	500	μA
	V _R = 45 V	T _A = 125 °C		5	15	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	VT1045C	VIT1045C	UNIT	
Turnical thermal registeriog	per diode	Р	3.5		°C/W	
Typical thermal resistance	per device	$R_{ extsf{ heta}JC}$	2.5			

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	VT1045C-M3/4W	1.87	4W	50/tube	Tube		
TO-262AA	VIT1045C-M3/4W	1.45	4W	50/tube	Tube		
TO-220AB	VT1045CHM3/4W (1)	1.87	4W	50/tube	Tube		
TO-262AA	VIT1045CHM3/4W (1)	1.45	4W	50/tube	Tube		

Note

⁽¹⁾ AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

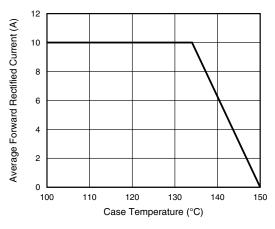


Fig. 1 - Maximum Forward Current Derating Curve

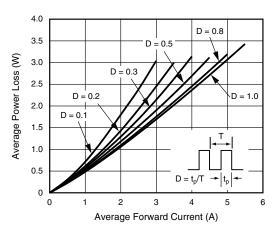


Fig. 2 - Forward Power Loss Characteristics Per Diode

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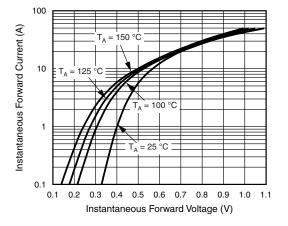


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

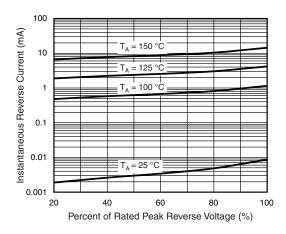


Fig. 4 - Typical Reverse Characteristics Per Diode

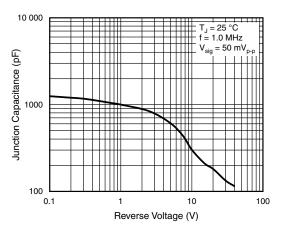


Fig. 5 - Typical Junction Capacitance Per Diode

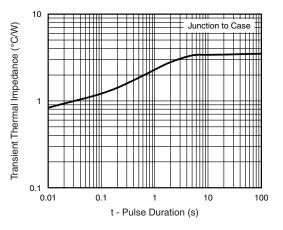


Fig. 6 - Typical Transient Thermal Impedance Per Diode

3

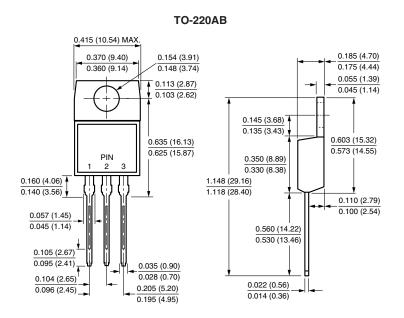
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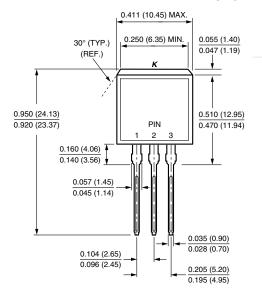
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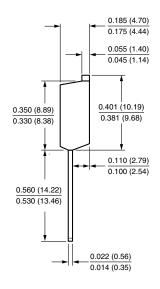


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA





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